

YJ Planar Schottky Barrier Diode Die Specification

60V 10A, 87mil, Schottky barrier diode die based on silicon planar process
Part No.: PSB087M060AS-280A

Main Products Characterstics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 10\text{ A}$

$\leq 2\%$

Device Schematics and Outline Drawing

- Die Thickness *
- Die Size **
- Top Metal Pad
- Active Area

Top Metal